

# **DESCRIPTION**

The GSM712 transient voltage suppressor (TVS) diode is designed for asymmetrical (12V to -7V) protection in multi-point data transmission standard RS-485 applications. The GSM712 may be used to protect devices from transient voltages resulting from electrostatic discharge (ESD), electrical fast transients (EFT), and lightning.

The GSM712 features 400 Watts (tp=8/20µs) of power handling capability to accommodate the higher transient voltage levels which may be expected in extended common mode applications. This provides higher equipment reliability and eliminates the "guess work" required when using zener diodes that are not rated to handle such transient conditions.

The integrated design aids in reducing voltage over-shoot associated with trace inductance. The low clamping voltage of the GSM712 minimizes the stress on the protected transceiver. The SOT-23 package allows flexibility in the design of "crowed" circuit boards.

# **FEATURES**

- ♦400 watts peak pulse power (tp=8/20µs)
- ♦ Transient protection for asymmetrical data lines to

IEC 61000-4-2 (ESD) ±15kV(air), ±8kV(contact)

IEC 61000-4-4 (EFT) 40A (5/50ns)

IEC 61000-4-5 (Lightning) 12A (8/20µs)

- ♦ Protects two +12V to -7V lines
- ♦Low capacitance
- ♦Low leakage current
- ♦Low clamping voltage
- ♦ Solid-state silicon avalanche technology
- ♦RoHS compliant

# **MACHANICAL DATA**

- ♦SOT-23 package
- ♦Flammability Rating: UL 94V-0
- ♦ Terminal: Matte tin plated.
- ♦ Packaging: Tape and Reel
- ♦High temperature soldering guaranteed: 260°C/10s
- ♦Reel size: 7 inch

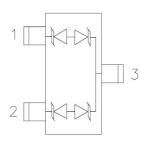
### ORDERING INFORMATION

Device: GSM712
Package: SOT-23
Marking: 712 or C72
Material: Halogen free
Packing: Tape & Reel
Quantity per reel: 3,000pcs

# **APPLICATIONS**

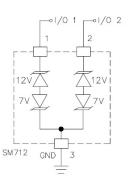
- ♦ Protection of RS-485 transceivers with extended common-mode range
- ♦ Automatic Teller Machines
- ♦HFC systems
- ♦ Networks

# **PIN CONFIGURATION & SCHEMATIC**



SOT23 (Top View)

# **CIRCUIT DIAGRAM**





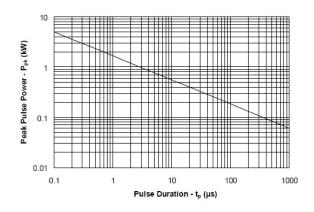
ABSOLUTE MAXIMUM RATING						
Symbol	Parameter	Value	Units			
P <sub>PP</sub>	Peak Pulse Power (8/20µs)	400	W			
I <sub>PP</sub>	Peak Pulse Current (8/20µs)	17	Α			
V <sub>ESD</sub>	ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	±15 ±8	kV			
T <sub>OPT</sub>	Operating Temperature	-55/+150	°C			
T <sub>STG</sub>	Storage Temperature	-55/+150	°C			

ELECTRICAL CHARACTERISTICS (Tamb=25°C)									
Symbol	Parameter	Test Condition	Pin 1 to 3 and Pin 2 to 3 (12V) TVS		Pin 3 to 1 and Pin 3 to 2 (7V TVS)		Units		
			Min	Тур	Max	Min	Тур	Max	
$V_{RWM}$	Reverse Working Voltage	Pin 3 to 1 or Pin 2 to 1			12			7	V
$V_{BR}$	Reverse Breakdown Voltage	I <sub>T</sub> = 1mA	13.3			7.5			V
I <sub>R</sub>	Reverse Leakage Current	$V_R = V_{RWM}$			1			20	μΑ
V <sub>C1</sub>	Clamping Voltage 1	$I_{PP} = 5A,$ $t_p = 8/20 \mu s$			20			12	V
V <sub>C2</sub>	Clamping Voltage 2	$I_{PP} = 17A,$ $t_p = 8/20 \mu s$			26			16	V
C <sub>J1</sub>	Junction Capacitance 1	V <sub>R</sub> = 0V, f = 1MHz			75			75	pF
$C_{J2}$	Junction Capacitance 2	$V_R = V_{RWM},$ $f = 1MHz$		45	_		45		pF

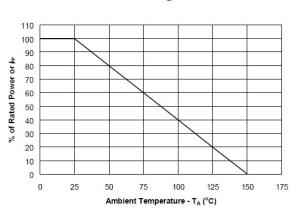


# **ELECTRICAL CHARACTERISTICS CURVE**

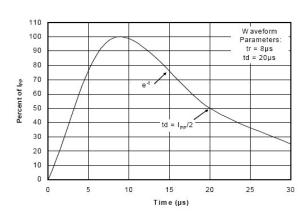
### Non-Repetitive Peak Pulse Power vs. Pulse Time



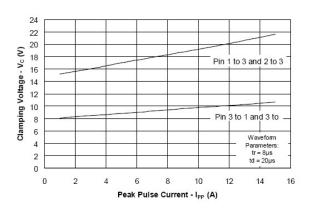
### **Power Derating Curve**



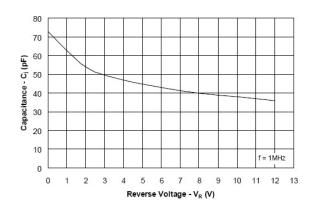
### **Pulse Waveform**



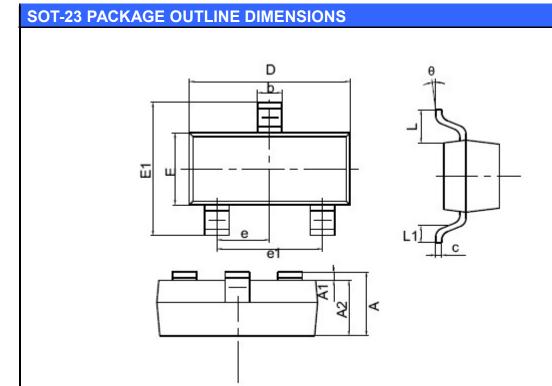
Clamping Voltage vs. Peak Pulse Current



# Capacitance vs. Reverse Voltage







symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950REF.		0.037REF.		
e1	1.800	2.000	0.071	0.079	
L	0.550REF		0.022REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	